Electronic Supplementary Information

Densely-packed hybrid films comprising SnO₂ and reduced graphite oxide for high**density electrochemical capacitors**

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Fig. S1 FT-IR spectra of GO, rGO and SnO₂/rGO hybrid films. Even after thermal reduction at 200 °C, the hydroxyl group of GO were mostly eliminated, but carboxyl (C–O and C=O) remained inside the rGO film. The various peaks in the figure indicate that the carboxylic stretching vibration, O–H bending vibration, sp² carbon, epoxide C–O stretching, alkoxy C–O bonding, O–Sn–O symmetric stretching located at 1729, 1619, 1577, 1224, 1045, and 665 cm⁻¹, respectively.¹⁻⁴

There is a study regarding the formation of $SnO₂$ NPs on multi-walled carbon nanotubes using a simple chemistry.⁵ This work proposed a possible reaction mechanism between $SnCl₂$ and $O₂$

(dissolved in the water) in HCl solution. From this proposed reaction, it is deduced that oxygen species in the reaction would be originated from oxygen functional groups of GO. As examined by FT-IR spectra, $SnO₂/rGO$ hybrid had much less hydroxyl groups than other functional groups such as carboxyl and epoxide groups. Therefore, it is deduced that one of the oxygen functional groups, especially, hydroxyl group (–OH) might be mainly bound with Sn^{2+} ions to form $SnO₂$ NPs on GO sheets. From our investigation, the possible reaction mechanism of the chemical redox reaction between GO and the $SnCl₂$ precursor will be proposed as follows:

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O_2 \left(\text{from GO} \right) + 2SnCl_2 + 2H_2O \rightarrow 2SnO_2 \left(\text{on GO} \right) + 4HCl
$$

Fig. S2 Thermal gravimetric analysis for bare rGO and various $SnO₂/rGO films$. The x (10, 16, 26, and 32) weight percent of $SnO₂$ in the hybrid is described as the x $SnO₂/rGO$.

Fig. S3 SEM images of the surfaces of the (a) rGO and (b) SnO₂/rGO films. A magnified image of the hybrid film is shown in the inset of Figure S1b. The hybrid film exhibited a sheet morphology that was similar to that of the rGO film, but the hybrid film contained some wrinkles due to the presence of the SnO2 NPs in the rGO sheets.

Fig. S4 TEM images of the surfaces of various SnO₂/rGO hybrids. (a) 16 SnO₂/rGO, (b) 32 SnO₂/rGO and (c) 10 SnO₂/rGO. High-resolution TEM images of each sample are shown in (d), (e), and (f), respectively. The images indicate that sub-5-nm-diameter $SnO₂$ particles were formed on the rGO surfaces.

Fig. S5 SEM images of various forms of $SnO₂/rGO$ hybrids. (a) 16 $SnO₂/rGO$ hybrid film, (b) a region of the cracked 32 SnO₂/rGO film, (c) a powder form of SnO₂/rGO and (d) its magnified region.

The SnO₂ NPs were uniformly decorated on both the rGO surfaces and edges, and they formed a compact film structure below 32 wt% $SnO₂$ in the hybrid (Fig. S5a). However, as seen in the Fig. S5b, cracks were observed in the $SnO₂/rGO$ film with 32 wt % $SnO₂$, and furthermore, above 32 wt % SnO2 in the hybrid, SnO2/rGO hybrid started to be aggregated into particles as seen in the Fig. S5c– d. Although the powder form of $SnO₂/rGO$ had a different morphology than other hybrids below 32 wt% $SnO₂$, it showed still uniform distribution of $SnO₂$ NPs in the hybrids, supported by the elemental mapping images of the Fig. S6.

Fig. S6 (a) SEM image of the powder form of SnO₂/rGO hybrid. Energy-dispersive X-ray spectroscopy (EDS) elemental mapping of the hybrid; (b) overlay, (c) tin (pink dots), (d) carbon (green dots), and (e) oxygen (yellow dots) elemental mapping images.

Fig. S7 Cross-sectional SEM images of the rGO and various SnO₂/rGO compact films. The film thicknesses of each film were estimated from the areas bounded by the yellow lines divided by the film length (ca. 11.7 μm).

Fig. S8 (a) XRD spectra of the rGO and SnO_2/rGO compact films. For the 32 SnO_2/rGO , a large piece of the cracked film was selected for the XRD measurement. The $SnO₂$ peaks indicated by red arrows correspond to cassiterite $SnO₂$ peaks; these were in good agreement with JCPDS No. 41– 1445. The black line indicates the rGO peaks, and (b) the estimated rGO interlayer spacing was increased as introducing more $SnO₂ NPs$ in the hybrids. This indicates the role of $SnO₂ NPs$ acting as effective spacers to prevent the restacking of rGO sheets.

Fig. S9 (a–b) BET N_2 adsorption-desorption isotherms of the rGO and various SnO_2/rGO films. (c) The corresponding BJH pore size distribution curves of all samples, and (d) summarized surface area characterization results.

Fig. S10 Cross-sectional TEM images of the 16 SnO₂/rGO film. (a) Low- and (b) high-resolution images. The inset of (b) is a typical selected area electron diffraction (SAED) pattern of polycrystalline SnO₂ nanoparticles.

Fig. S11 (a) CV curves of the various SnO_2/rGO hybrid films at 20 mV s⁻¹. (b) Volumetric, (c) areal and (d) gravimetric capacitances of the various $SnO₂/rGO$ films as a function of scan rate. These tests were conducted in an acidic electrolyte of 1 M H₂SO₄.

Fig. S12 (a) Areal and (b) gravimetric capacitances of bare rGO and 16 SnO₂/rGO in different electrolytes.

Fig. S13 Charge/discharge curves of the (a–b) rGO and (c-d) optimized SnO₂/rGO films in acidic and neutral electrolytes.

Fig. S14 Nyquist plots of (a) rGO and (b) optimized SnO_2/rGO films in various aqueous electrolytes. The insets correspond to the high frequency regions. The corresponding Bode plots of the (c) rGO and (d) optimized SnO_2/rGO films. The 16 SnO_2/rGO film exhibited a greatly enhanced ion transport property in various aqueous electrolytes compared with the bare rGO film.

Fig. S15 (a) Nyquist and (b) Bode plots of various SnO₂/rGO films in an acidic electrolyte of 1 M H2SO4. The inset corresponds to the high frequency region of the Nyquist plot. These plots indicated that the optimum loading amount of $SnO₂$ in the hybrid was ca. 16–26 wt% $SnO₂$.

Sample	$R_s(\Omega)$	$R_{ct}(\Omega)$	$R_{ESR}(\Omega)$	C_{dl} (mF)
rGO in H_2SO_4	1.50	61.01	62.51	0.27
rGO in K_2SO_4	0.91	16.16	17.07	6.98
rGO in $Na2SO4$	0.99	85.20	86.19	1.93
rGO in KOH	0.65	1.56	2.21	83.20
16 SnO ₂ /rGO in H_2SO_4	0.69	2.34	3.03	52.39
16 SnO ₂ /rGO in K_2SO_4	0.89	2.33	3.22	49.53
16 SnO ₂ /rGO in Na ₂ SO ₄	0.95	5.86	6.81	38.28
16 SnO ₂ /rGO in KOH	0.74	1.98	2.72	79.06

Table S2. Detailed Nyquist plot fitting results for rGO and 16 SnO₂/rGO films.

Fig. S16 Equivalent circuit for fitting of the Nyquist plot for the bare rGO and SnO_2/rGO films. R_s : solution resistance, R_{ct} : charge transfer resistance, C_{d} : double layer capacitance, CPE: constant phase element, *Zw*: Warburg impedance.

Supplementary References

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